Junction FETs

DSK9J01×0L

Panasonic

DSK9J01×0L

Silicon N-channel Junciton FET

For low frequency amplification / For pyroelctric sensor DSK5J01 in SSMini3 type package

■ Features

- · High gate-drain Voltage(Source open)VGDO
- Halogen-free / RoHS compliant (EU RoHS / UL-94 V-0 / MSL:Level 1 compliant)

■ Marking Symbol: B6

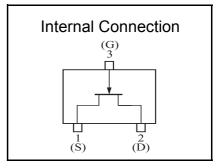
■ Packaging

Embossed type (Thermo-compression sealing): 3 000 pcs / reel (standard)

Unit: mm 1.6 0. 26 85 0 (0.5) (0.5) 1.0 1. Source 2. Drain 3. Gate Panasonic SSMini3-F3-B JEITA SC-89 SOT-490 Code

■ Absolute Maximum Ratings Ta = 25 °C

Parameter	Symbol	Rating	Unit
Gate-drain voltage (Source short)	VGDS	-55	V
Drain current	ID	30	mA
Gate current	IG	10	mA
Power dissipation	PD	125	mW
Channel temperature	Tch	150	°C
Operating ambient temperature	Topr	-40 to +85	°C
Storage temperature	Tstg	-55 to +150	°C



■ Electrical Characteristics Ta = 25 °C ± 3 °C

Parameter	Symbol	Conditions	Min	Тур	Max	Unit
Gate-drain voltage (Source short)	VGDS	IG = -100 μA, VDS = 0	-55			V
Drain current *1	IDSS	VDS = 10 V , VGS = 0	1.0		6.5	mA
Gate-source cutoff current	IGSS	VGS = -30 V, VDS = 0			-10	nA
Gate-source cutoff voltage	VGSC	VDS = 10 V, ID = 10 μA			-5	V
Forward transfer admittance	Yfs	VDS = 10 V, ID = 5 mA, f =1 kHz	2.5	7.5		mS
Small-signal short-circuit input capacitance	Ciss	- VDS = 10 V, VGS = 0, f = 1 MHz		6.0		pF
Small-signal reverse transfer capacitance	Crss			2.5		pF

Note) Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 Measuring methods for transistors.

*1 Rank classification

Code	Р	Q		
Rank	Р	Q		
IDSS (mA)	1.0 to 3.0	2.0 to 6.5		
Marking symbol	B6P	B6Q		

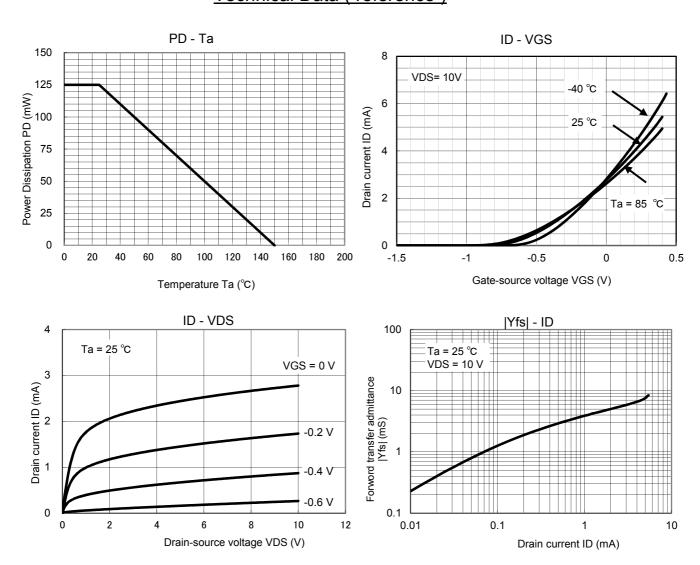
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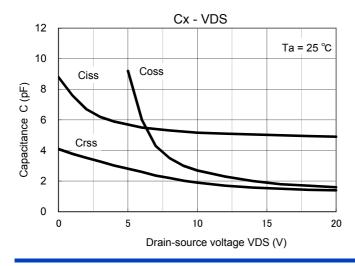
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Technical Data (reference)





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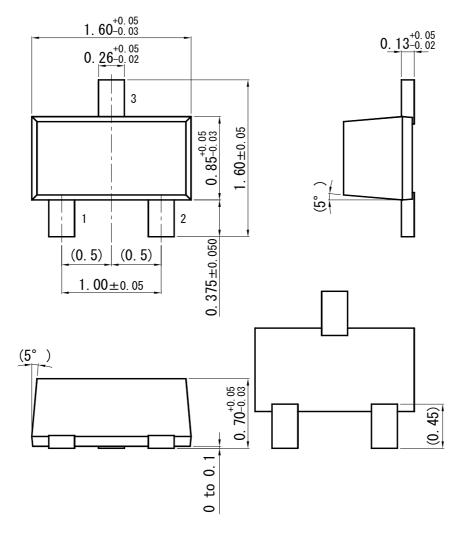
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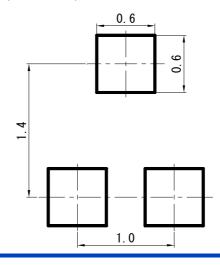
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SSMini3-F3-B

Unit: mm



■ Land Pattern (Reference) (Unit: mm)



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Established: 2010-09-07 Revised: 2014-03-25

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